NSN 5961-01-169-6047

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-169-6047 **Inclosure Material:** Metal **Overall Length:** 0.160 inches **Terminal Length:** 0.800 inches **Overall Diameter:** 0.100 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 working peak reverse voltage **Current Rating Per Characteristic:** 200.00 microamperes forward current, average major and 1.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 01526-44a354891 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No